

# ITRS Factory Integration

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## **2008 Contributors:**

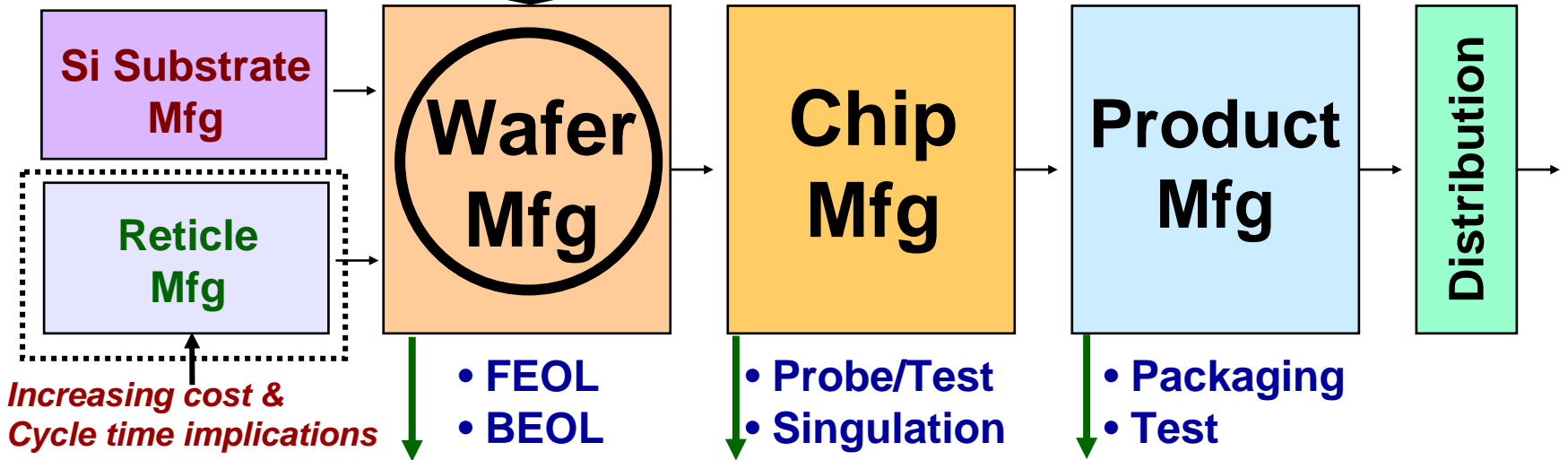
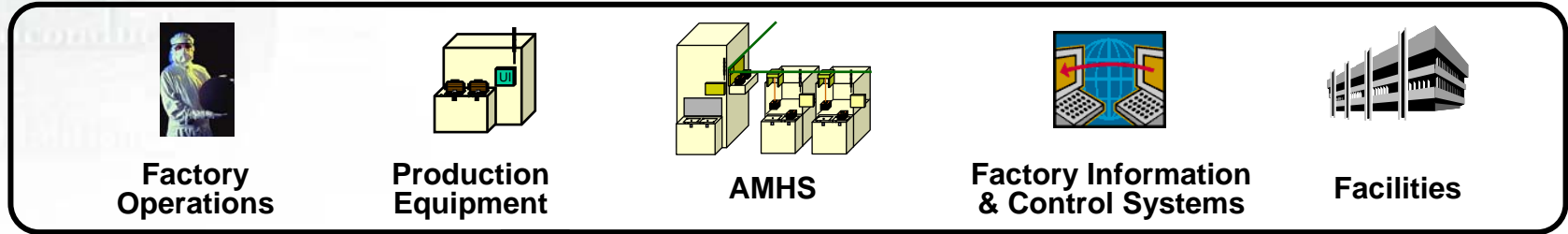
Terry Francis, Gopal Rao, Al Chasey, Les Marshall, Todd Lasater, Brad van Eck, Kenjiro Nawa, Daniel Babbs, Dave Eggleston, Mutaz Haddadin, Gavin Rider, Andreas Neuber, Eric Englhardt, Peter Csatory, Adrian Pyke, Mikio Otani, Bill Fosnight, Richard Oeschner  
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## **Global Co-Chairs:**

**Europe:** Arie Greenberg  
**Japan:** Shige Kobayashi, Michio Honma  
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**Taiwan:** Thomas Chen  
**US:** Tom Jefferson



# Factory Integration Scope and Drivers



## Factory is driven by Cost, Quality, Productivity, Speed, and Flexibility

- ☞ Reduce factory capital and operating costs per function
- ☞ Faster delivery of new and volume products to the end customer
- ☞ Efficient/Effective volume/mix production, high reliability, & high equipment reuse
- ☞ Enable rapid process technology shrinks and wafer size changes



# Key Technologies that will Impact Factory Design

- ★ 2008 and future years are targeted to meet productivity and capture technology requirements
- ★ Key process & device technology intercepts that will impact the factory design are Extreme Ultraviolet Litho (EUVL), new materials, 450mm conversion, significant productivity improvements, and waste (inefficiencies) reduction
- ★ Economic and business challenges are equal to our manufacturing and process technology challenges in scope and breadth to attain efficiency and effectiveness

	Near Term Years			
Year	2008	2009	2010	2011
Technology trend (nm)	65	55	50	45
Wafer Size (mm)	300	300	300	300

● Planning for NGF/450mm →

	Long Term Years										
Year	2012	2013	2014	2015	2016	2017	2018	2019	2020	2021	
Technology trend (nm)	40	35	32	28	25	22	20	18	16	14	
Wafer Size (mm)	450	450	450	450	450	450	450	450	450	450	

EUVL in Production?

450mm ?  
NGF ?



# FI 2008 Focus

Enable the Transition to NGF / 450mm for cost, cycle time & productivity improvement

2008 Topics	Result
1 Incorporate waste (inefficiency) reduction as part of FI roadmap	<ul style="list-style-type: none"><li>-Defined initial factory integration high level metrics for creation of a waste reduction roadmap<ul style="list-style-type: none"><li>-Equipment Output Waste</li><li>-Wait Time Waste</li></ul></li><li>-Completed initial draft of package to communicate waste reduction roadmap approach</li></ul>
2 Improve data quality, & time to information	<ul style="list-style-type: none"><li>- Defined strategy for integrating time synchronization and data handling requirements between production equipment and factory information and control systems.</li></ul>
3 Develop Facilities modeling methodology	<ul style="list-style-type: none"><li>- Initial development of a modeling methodology for evaluating factory size and cost relationship</li></ul>
4 FOUP Airborne Molecular Contamination (AMC) requirements	<ul style="list-style-type: none"><li>- In conjunction with the Yield Enhancement TWG, reached consensus on monitoring and control methods, and developed initial requirements</li></ul>



# FI 2009 Focus

Enable the Transition to NGF / 450mm for cost, cycle time & productivity improvement

	Focus Areas	2009 Goals
1	Incorporate waste reduction as part of FI roadmap	Inclusion of initial high level Waste Reduction metrics and roadmap in FI Technical Requirements tables
2	Improve data quality, & time to information	Definition of requirements for equipment and factory data handling rates to improve equipment and productivity monitoring
3	Airborne Molecular Contamination Requirements	Incorporate AMC limits for wafer carriers into technical roadmaps and document potential solutions
4	Facility Modeling Methodology	Completion of a functional model validated against benchmarked data
5	Address FI Cross-cut issues	Address NGF/450mm and identify common areas of waste reduction needs and challenges. Address FI key issues with FEP (Carrier Purging), Litho (Reticle Electrostatic Field, Double Patterning), ESH (Energy conservation), YE (AMC, PCS for Yield) and Metrology (Wafer map standards).



Other Focus Areas will be Addressed as Required

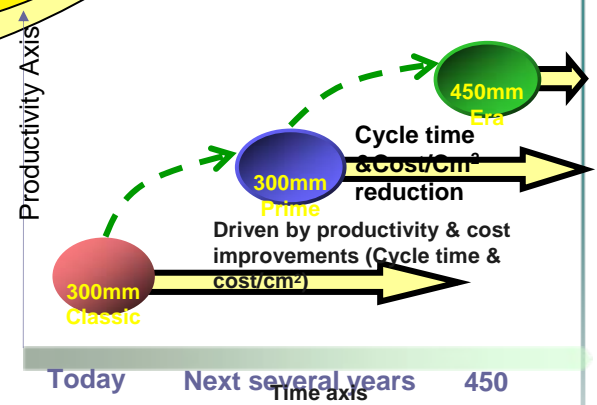
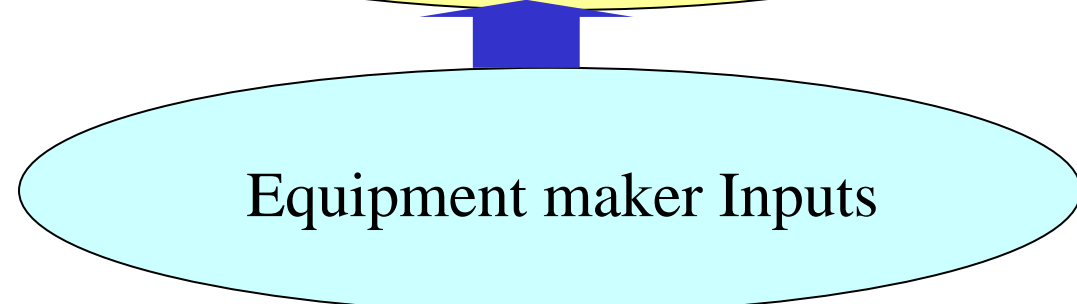
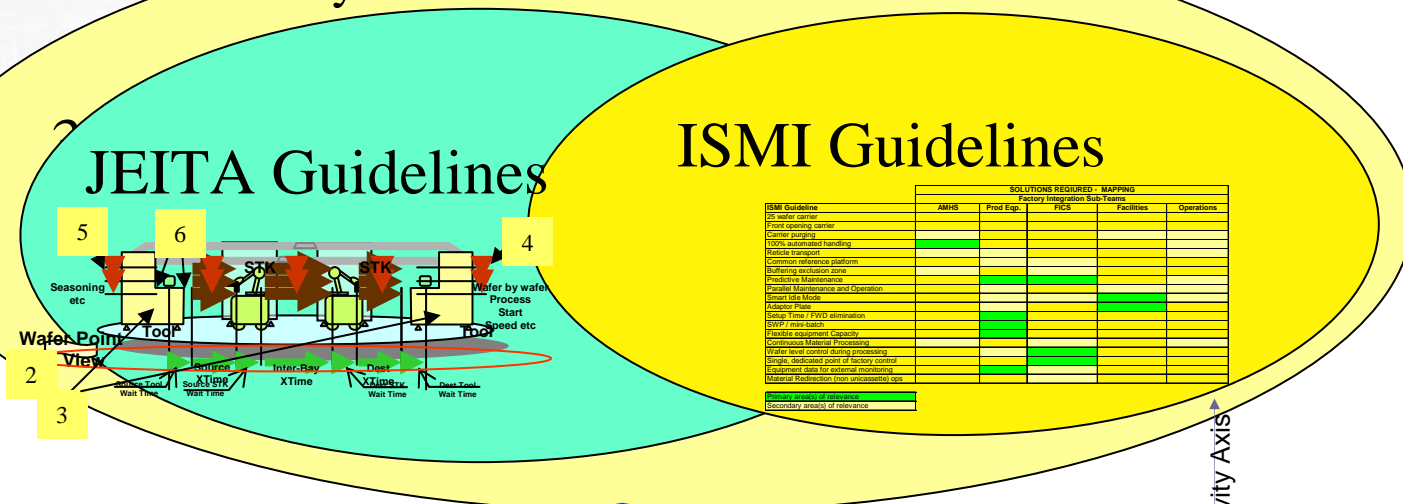
# Supporting Materials

## For ITRS Factory Integration 2008 and 2009 Focus Areas

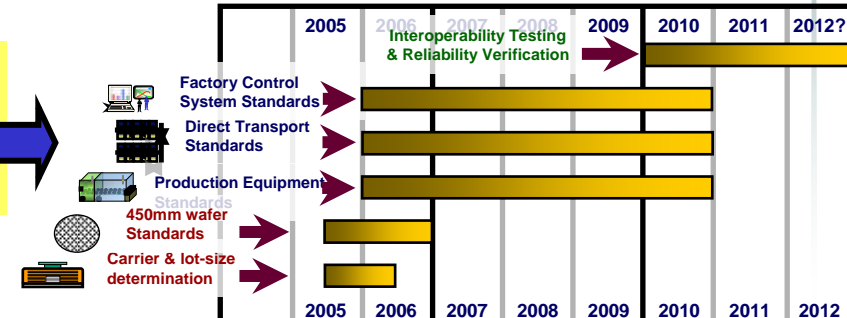


# NGF/450mm Fab Guidelines

NG Factory Guidelines combined with ITRS TR & PS



**ITRS FI TWG will synchronize with NGF and 450mm guidelines to address FI challenges, technology requirements and potential solutions**



# More Detailed Representation of Factory Waste

*Factory Integration  
Working Group Focus*

**Factory  
View**

<i>Wait time Waste</i>	<i>Equipment Output Waste in Factory</i>	<i>People Output Waste in Factory</i>
<i>Silicon Waste</i>	<i>Equipment Resource Waste</i>	<i>People Capability Waste</i>

**Unit  
View**

**Wafer**

**Equipment**

**People**



# Waste Reduction Activity Time Table

	2008				2009							
	July	Aug-Oct	Nov	Dec	Jan	Feb	Mar	April	May	Jun	July	
ITRS Events	★ Summer Mtg			★ Winter Mtg				★ Spring Mtg				★ Summer Mtg
2008 Focus Area manuscript	Manuscript											
Winter meeting preparation	Work with other TWGs to pilot W/R											
Material for IRC consideration				Review of W/R approach								
Spring meeting preparation				Final W/R TR tables development			Working with Other TWGs					
Finalizing '09 ITRS								W/R Write Up for 2009 ITRS				

# Wait Time (WTW) and Equipment (EOW) Output Waste

**Issue: Comprehensive data collection of factory resource activities**

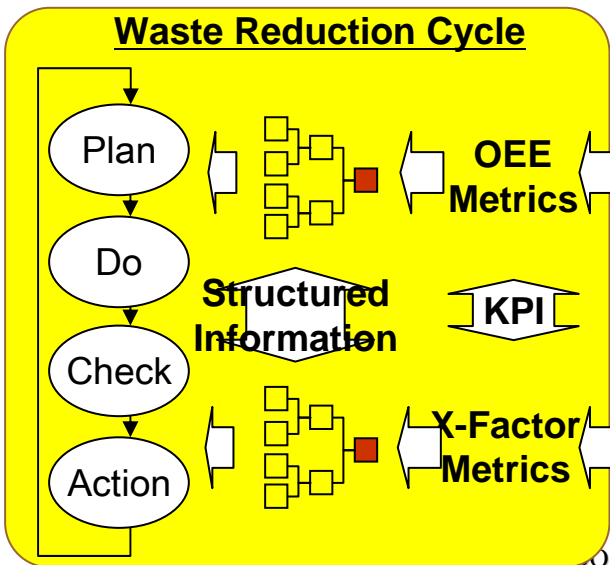
Addition of related factory resource activity data(; equipment, AMHS, operators, facility)

Standardization of data definition

Data collection automation

W/R :Waste Reduction  
 WTW :Wait Time Waste  
 EOW :Eqp Output Waste

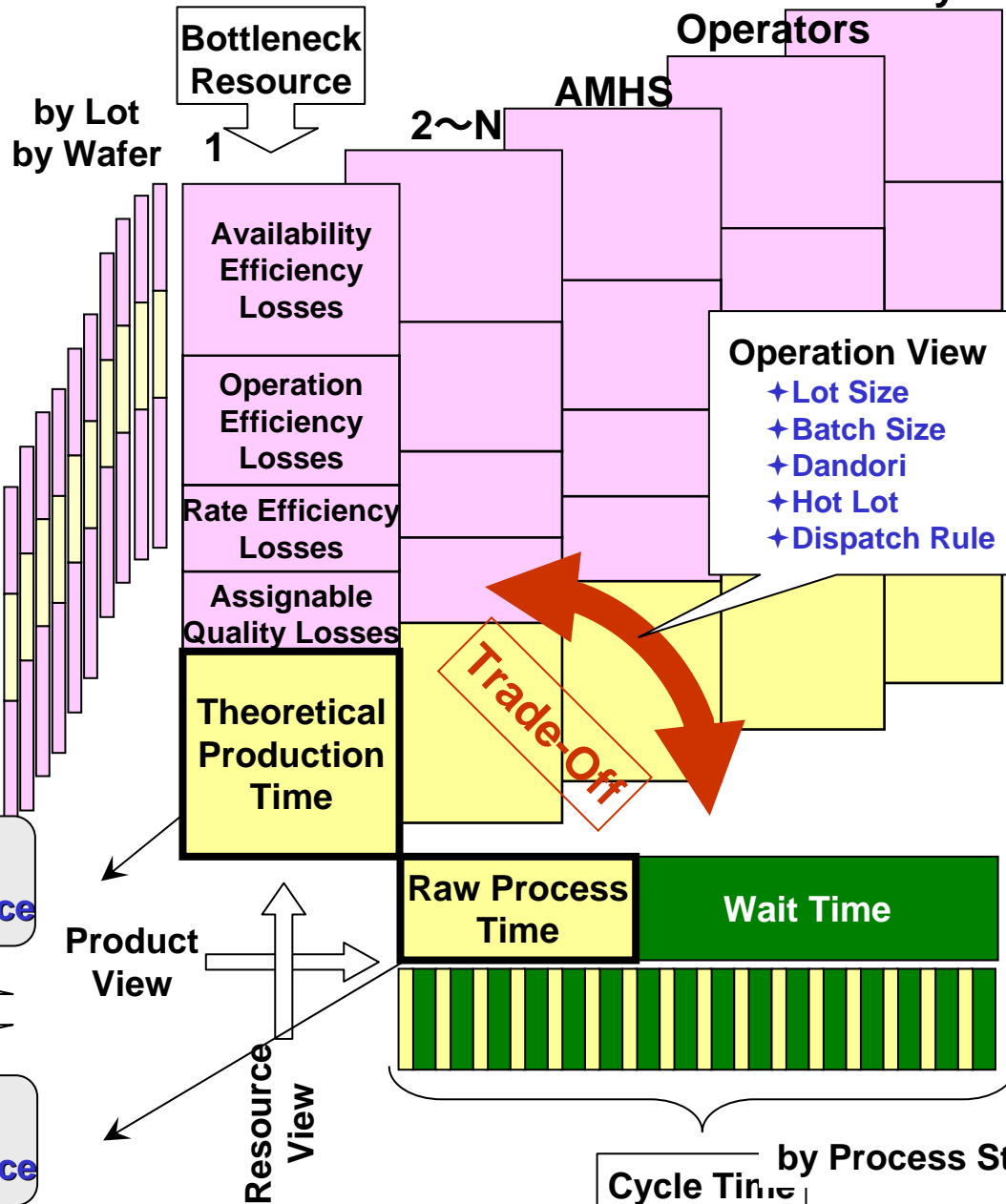
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EOW Reference

W/R

WTW Reference



# Applying Waste Reduction to Drive The Industry in the Proper Direction

## ★ Wait Time Waste

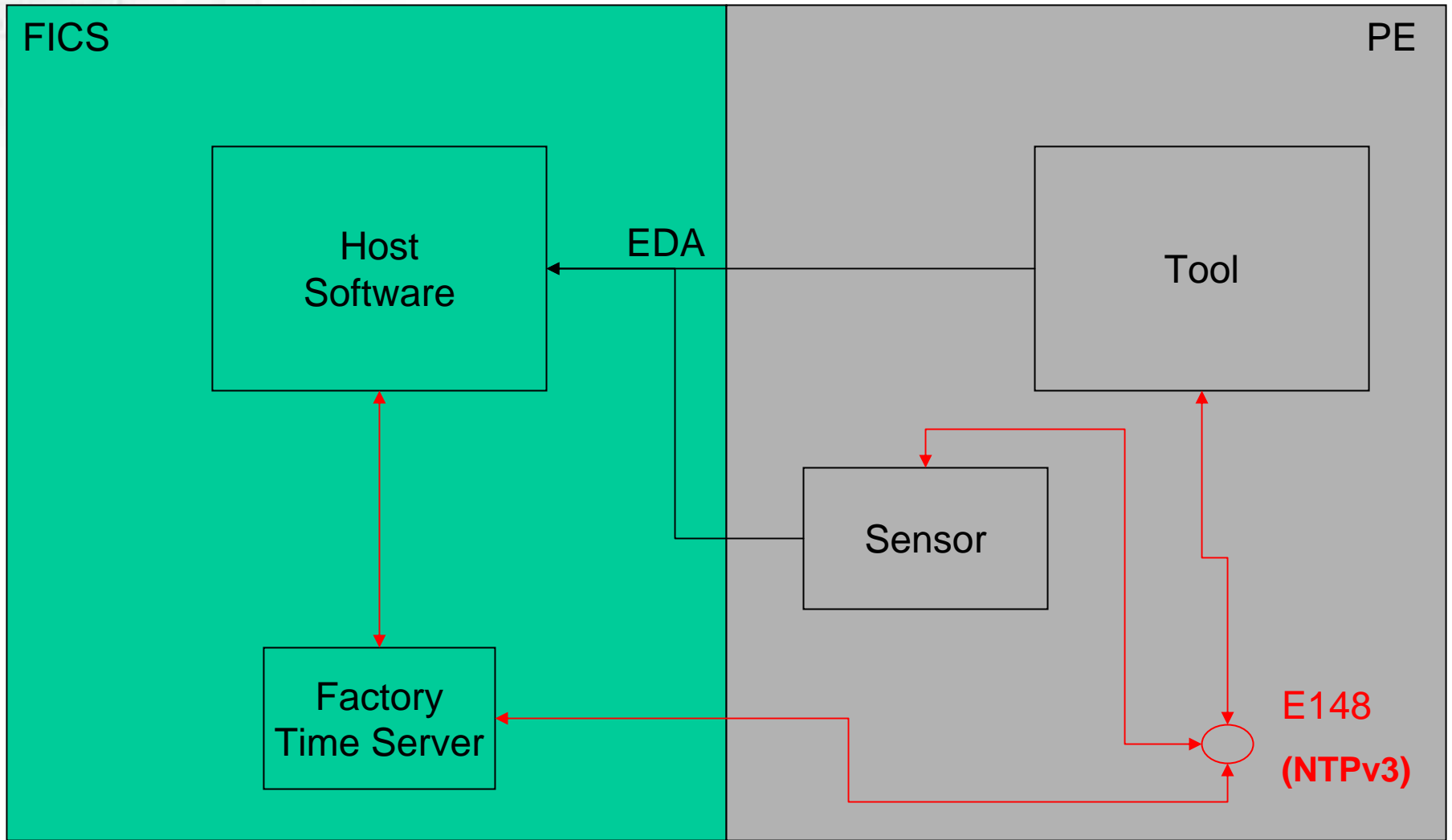
- ☞ **Baseline = time to process a single wafer in an un-loaded tool = CTmin**
- ☞ **Actual performance = cycle time of wafer when processed in production with large lot**
- ☞ **Waste = (actual CT-CTmin)/CTmin**

## ★ Equipment Output Waste

- ☞ **Baseline = designed equipment output capability (wph)**
- ☞ **Actual performance = actual good production wafer output of the equipment in production**
- ☞ **Waste = (capacity-actual good wfrs)/capacity \* 100**

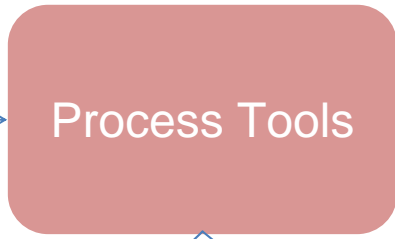


# Data Collection Roadmap

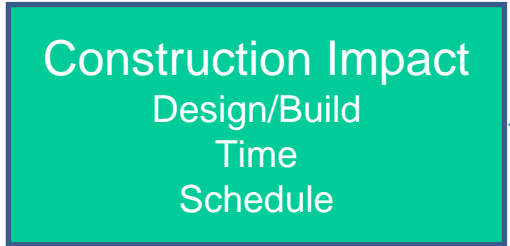
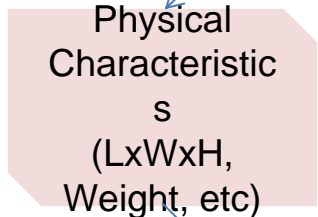


Data Frequency  
**Time Synchronization**  
Factory Integration

# Methodology for Future Facility Modeling High Level Approach



**HIGH LEVEL**  
First Draft  
Average Tool Size  
Tool Scaling Factor  
Admin Scaling Factor  
Support Space Scaling Factor  
Cost per square foot



# Total AMC Concept

